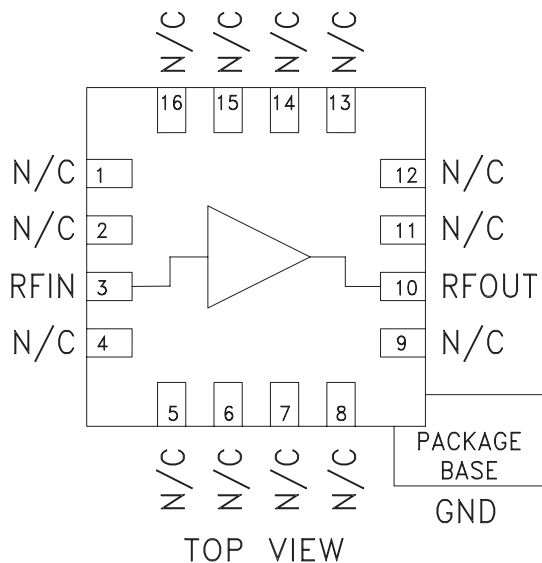


### Typical Applications

This amplifier is ideal for high linearity applications:

- Multi-Carrier Systems
- GSM, GPRS & EDGE
- CDMA & WCDMA
- PHS

### Functional Diagram



### Features

- Output IP3: +42 dBm
- Gain: 13 dB
- 56% PAE @ +28 dBm Pout
- +19 dBm W-CDMA Channel Power @ -45 dBc ACP
- 3x3 mm QFN SMT Package

### General Description

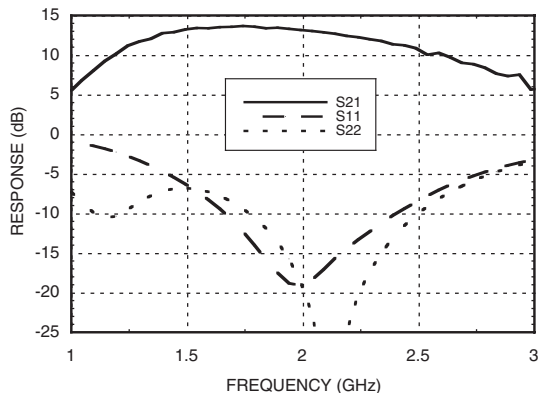
The HMC455LP3 & HMC455LP3E are high output IP3 GaAs InGaP Heterojunction Bipolar Transistor (HBT) 1/2 watt MMIC amplifiers operating between 1.7 and 2.5 GHz. Utilizing a minimum number of external components the amplifier provides 13 dB of gain and +28 dBm of saturated power at 56% PAE from a single +5 Vdc supply voltage. The high output IP3 of +42 dBm coupled with the low VSWR of 1.4:1 make the HMC455LP3 & HMC455LP3E ideal driver amplifiers for PCS/3G wireless infrastructures. A low cost, leadless 3x3 mm QFN surface mount package (LP3) houses the linear amplifier. The LP3 provides an exposed base for excellent RF and thermal performance.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , $V_S = +5\text{V}$

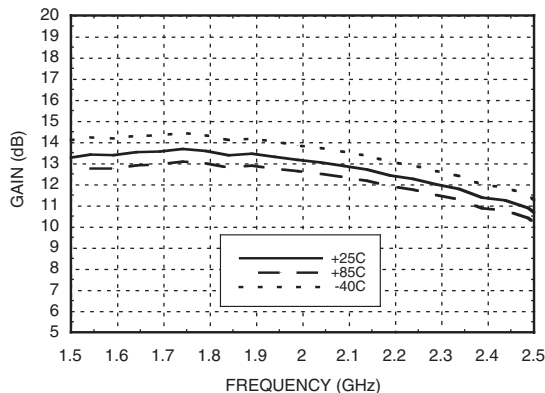
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	1.7 - 1.9			1.9 - 2.2			2.2 - 2.5			GHz
Gain	11.5	13.5		10.5	13		9	11.5		dB
Gain Variation Over Temperature		0.012	0.02		0.012	0.02		0.012	0.02	dB / °C
Input Return Loss		13			15			10		dB
Output Return Loss		10			18			15		dB
Output Power for 1dB Compression (P1dB)	24	27		24.5	27.5		23	26		dBm
Saturated Output Power (Psat)		28.5			28			27		dBm
Output Third Order Intercept (IP3)	37	40		39	42		37	40		dBm
Noise Figure		7			6			6		dB
Supply Current (Icq)		150			150			150		mA



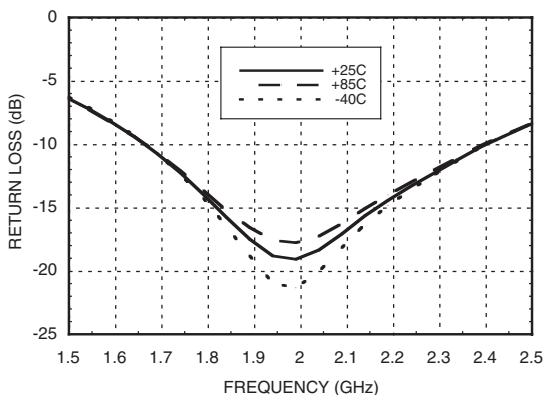
**Broadband Gain & Return Loss**



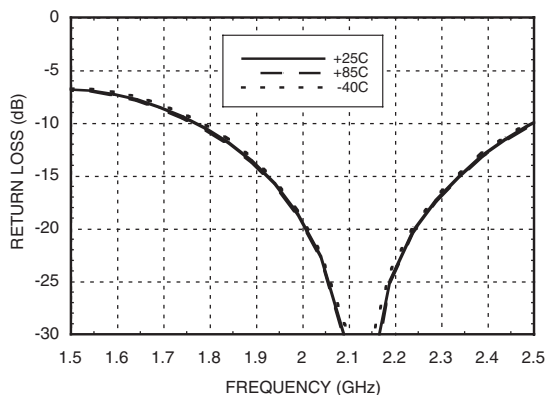
**Gain vs. Temperature**



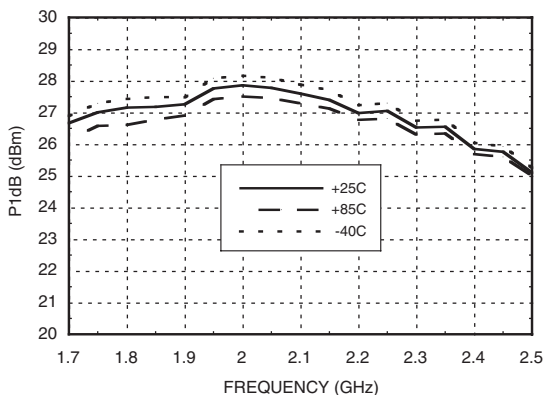
**Input Return Loss vs. Temperature**



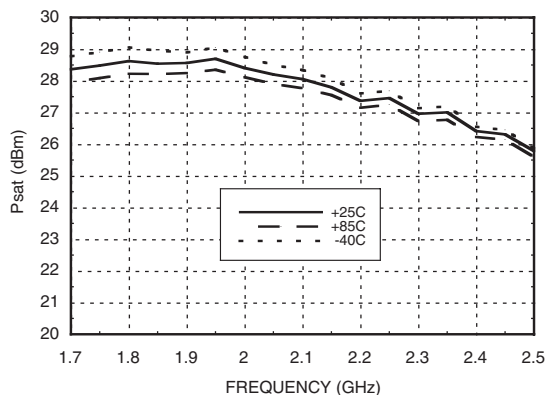
**Output Return Loss vs. Temperature**



**P1dB vs. Temperature**

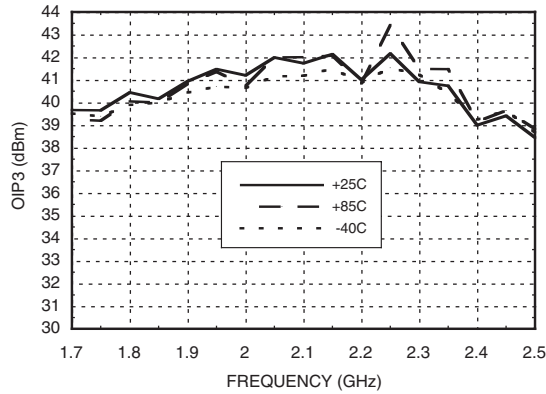


**Psat vs. Temperature**

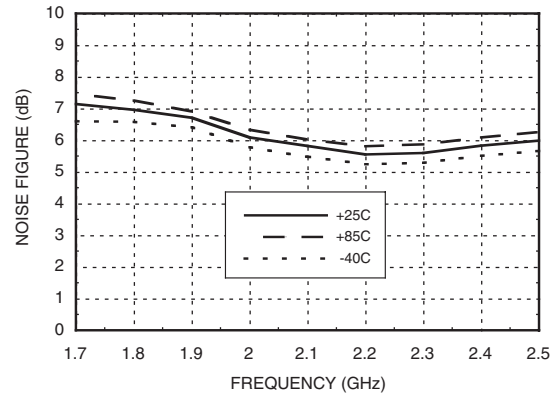


Data shown is tuned for 1.85 - 2.2 GHz, contact HMC  
Applications for recommended 1.7 - 1.85 GHz & 2.2 - 2.5 GHz tuning circuits.

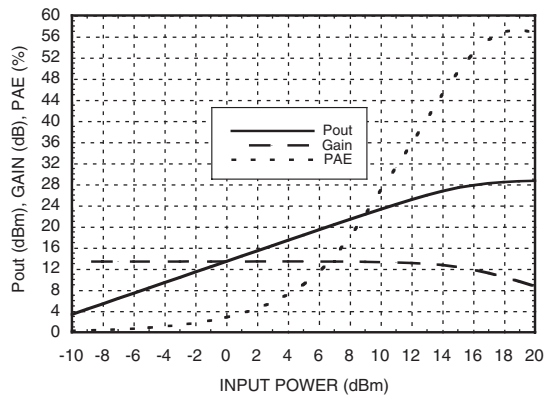
**Output IP3 vs. Temperature**



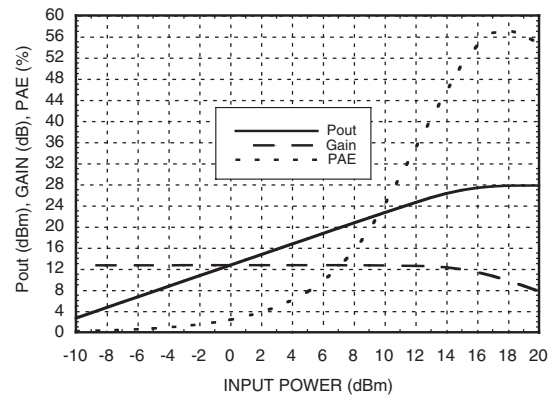
**Noise Figure vs. Temperature**



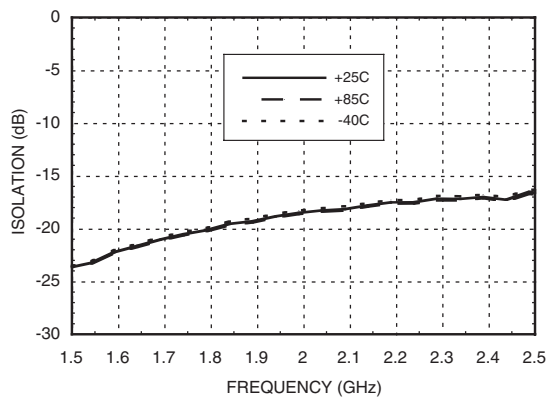
**Power Compression @ 1.95 GHz**



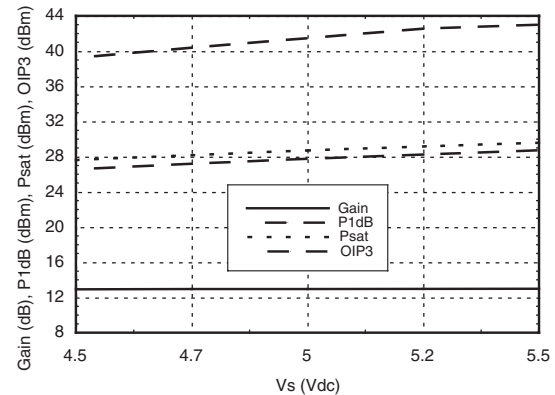
**Power Compression @ 2.15 GHz**



**Reverse Isolation vs. Temperature**



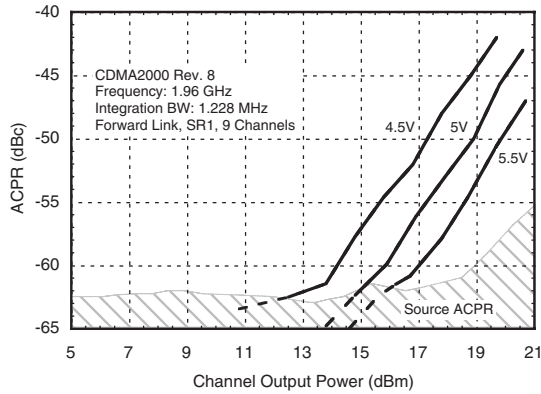
**Gain, Power & IP3 vs. Supply Voltage @ 1.95 GHz**



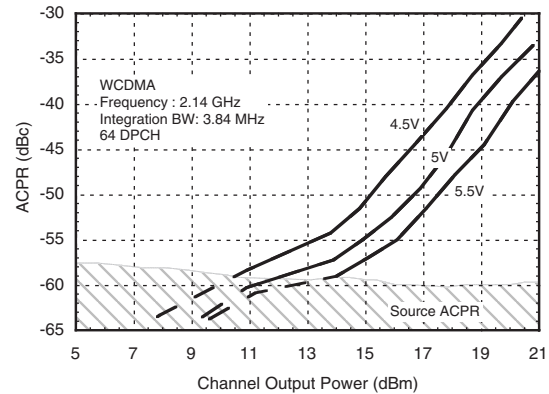
Data shown is tuned for 1.85 - 2.2 GHz, contact HMC  
Applications for recommended 1.7 - 1.85 GHz & 2.2 - 2.5 GHz tuning circuits.



### ACPR vs. Supply Voltage @ 1.96 GHz CDMA 2000, 9 Channels Forward



### ACPR vs. Supply Voltage @ 2.14 GHz W-CDMA, 64 DPCH



### Absolute Maximum Ratings

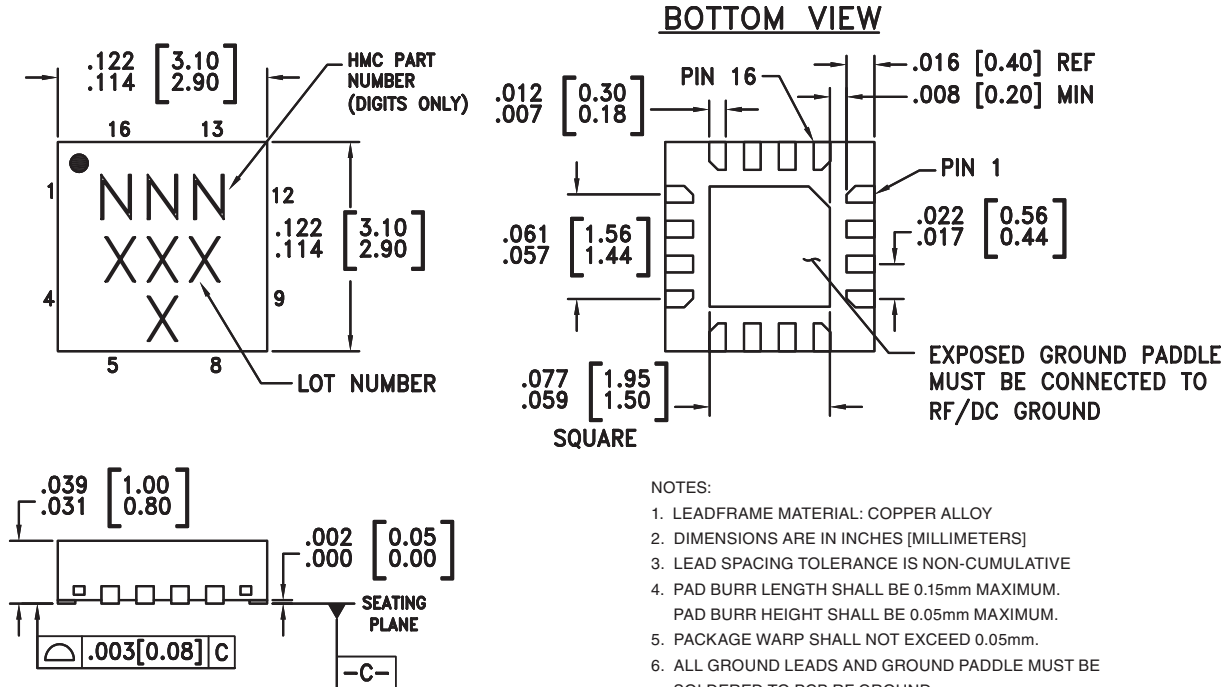
Collector Bias Voltage (Vcc)	+6.0 Vdc
RF Input Power (RFIn)(Vs = +5.0 Vdc)	+25 dBm
Junction Temperature	150 °C
Continuous P <sub>diss</sub> (T = 85 °C) (derate 16 mW/°C above 85 °C)	1.04 W
Thermal Resistance (junction to ground paddle)	63 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Data shown is tuned for 1.85 - 2.2 GHz, contact HMC  
Applications for recommended 1.7 - 1.85 GHz &  
2.2 - 2.5 GHz tuning circuits.



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

### Outline Drawing



### Package Information

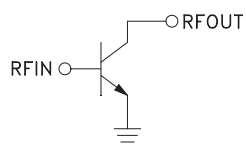

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC455LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	455 XXXX
HMC455LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	455 XXXX

[1] Max peak reflow temperature of 235 °C

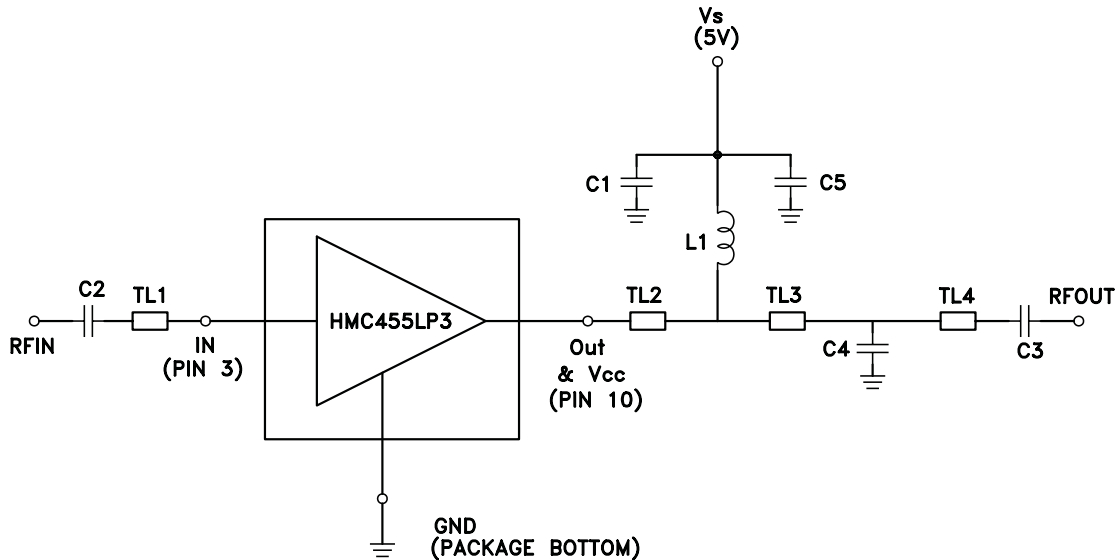
[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4 - 9, 11 - 16	N/C	This pin may be connected to RF ground.	
3	RFIN	This pin is AC coupled. An off chip series matching capacitor is required.	
10	RFOUT	RF output and DC Bias for the output stage.	
	GND	Package bottom must be connected to RF/DC ground.	

### Application Circuit



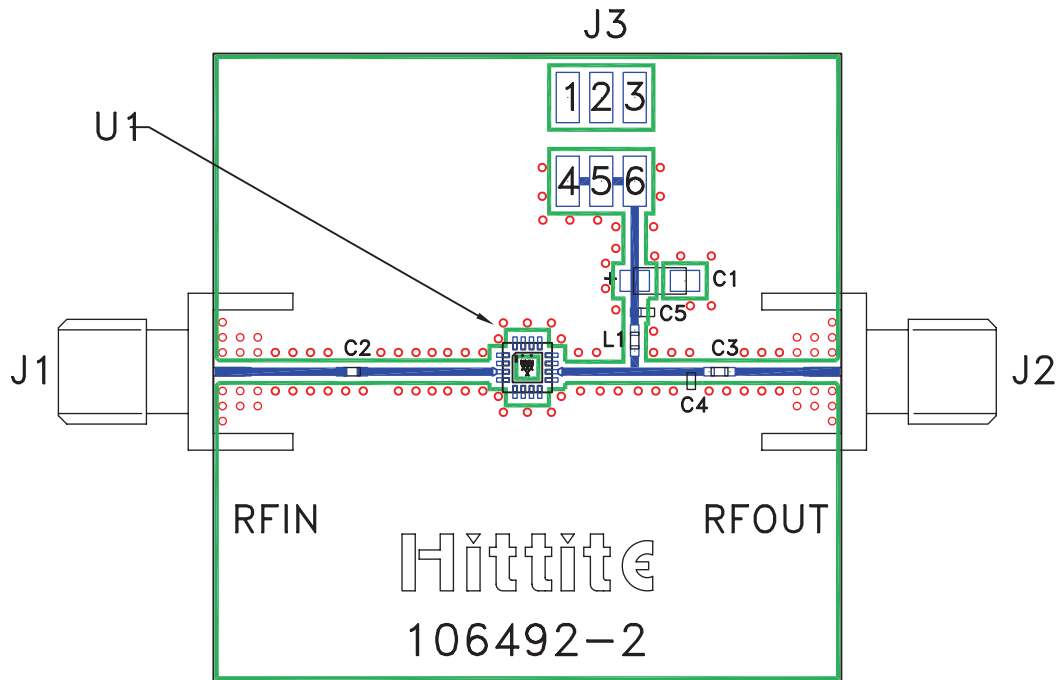
	TL1	TL2	TL3	TL4
Impedance	50 Ohm	50 Ohm	50 Ohm	50 Ohm
Physical Length	0.33"	0.18"	0.13"	0.04"
Electrical Length	34°	19°	13.5°	4°
PCB Material: 10 mil Rogers 4350, Er = 3.48				

Recommended Component Values	
L1	8.2 nH
C1	2.2 $\mu$ F
C2, C3	3.0 pF
C4	0.9 pF
C5	100 pF

Data shown is tuned for 1.85 - 2.2 GHz, contact HMC  
Applications for recommended 1.7 - 1.85 GHz & 2.2 - 2.5 GHz tuning circuits.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:  
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373  
Order On-line at [www.hittite.com](http://www.hittite.com)

### Evaluation PCB



J3

Pin Number	Description
1, 2, 3	GND
4, 5, 6	Vs

### List of Materials for Evaluation PCB 106058 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	2.2 $\mu$ F Capacitor, Tantalum
C2, C3	3.0 pF Capacitor, 0402 Pkg.
C4	0.9 pF Capacitor, 0402 Pkg.
C5	100 pF Capacitor, 0402 Pkg.
L1	8.2 nH Inductor, 0402 Pkg.
U1	HMC455LP3 / HMC455LP3E Power Amplifier
PCB [2]	106492 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of VIA holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

Data shown is tuned for 1.85 - 2.2 GHz, contact HMC

Applications for recommended 1.7 - 1.85 GHz & 2.2 - 2.5 GHz tuning circuits.



MICROWAVE CORPORATION v02.0605



## HMC455LP3 / 455LP3E

*InGaP HBT ½ Watt High IP3  
AMPLIFIER, 1.7 - 2.5 GHz*

**Notes:**

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AMPLIFIERS - SMT